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#	Paper	IF	Citations
2351	Tractable Approach for Calculating Lattice Distortions around Simple Defects in Semiconductors: Application to the Single Donor Ge in GaP. <i>Physical Review Letters</i> , 1982 , 49, 1765-1768	7.4	53
2350	A local density functional(L)CAO method with effective potentials for obtaining the electronic structure of molecules and clusters. 1983 , 98, 72-76		18
2349	AB-Initio calculation of chemical bonding in the low temperature phases of silver halides. 1983 , 9-10, 1389-1391		4
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2347	Mineral and melt physics a summary of research in the United States, 1979-1982. 1983 , 21, 1487		44
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2344	Ground-state properties of Ag ₂ : A local-density pseudopotential approach. <i>Physical Review A</i> , 1983 , 28, 3637-3639	2.6	17
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